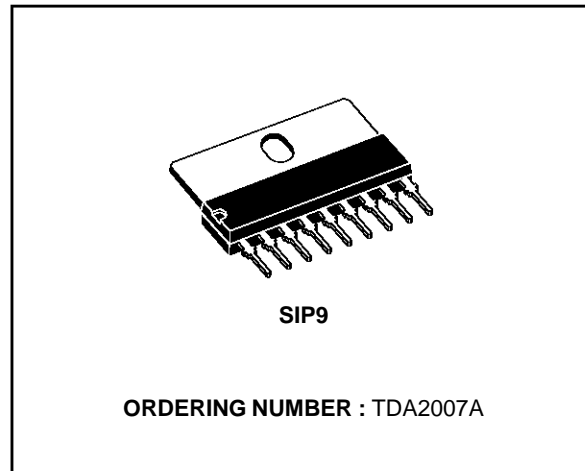


6 + 6W STEREO AMPLIFIER

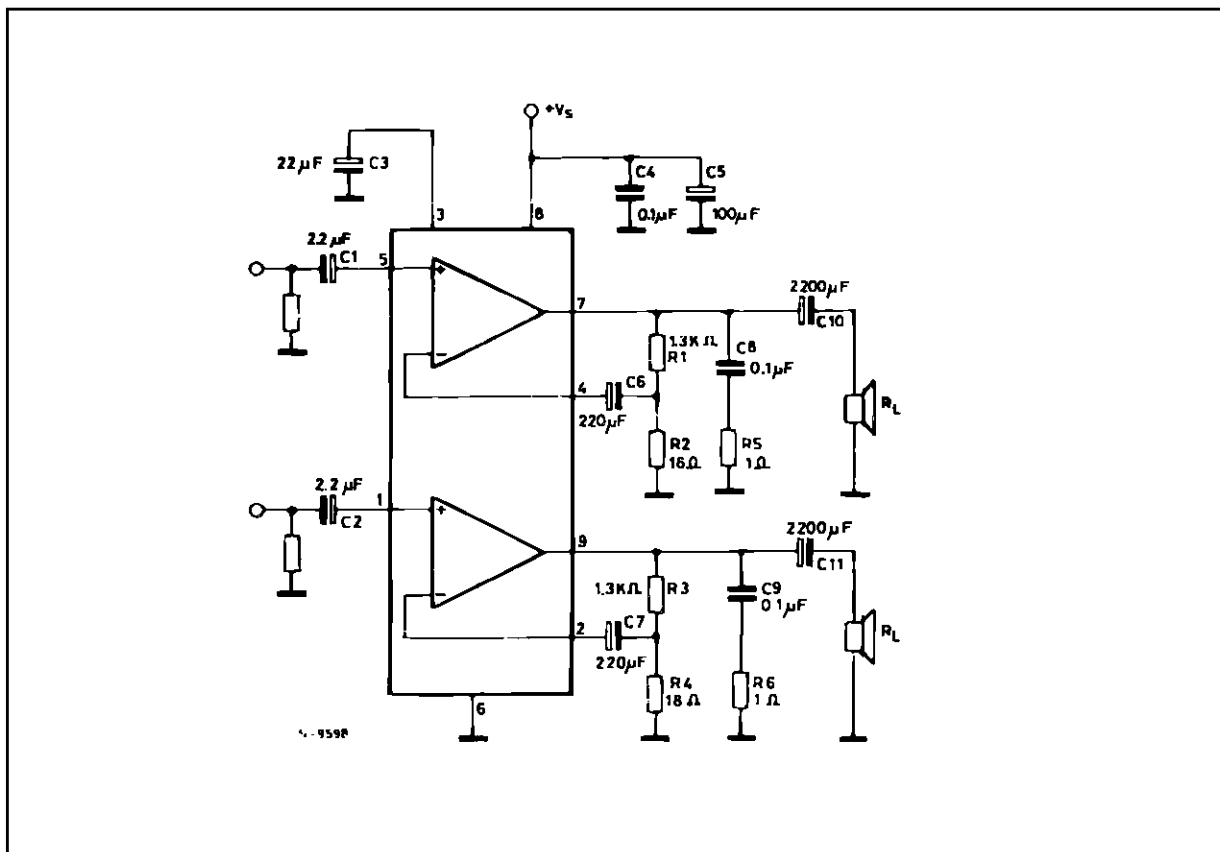
- HIGH OUTPUT POWER
- HIGH CURRENT CAPABILITY
- AC SHORT CIRCUIT PROTECTION
- THERMAL OVERLOAD PROTECTION

DESCRIPTION

The TDA2007A is a class AB dual Audio power amplifier assembled in single in line 9 pins package, specially designed for stereo application in music centers TV receivers and portable radios.

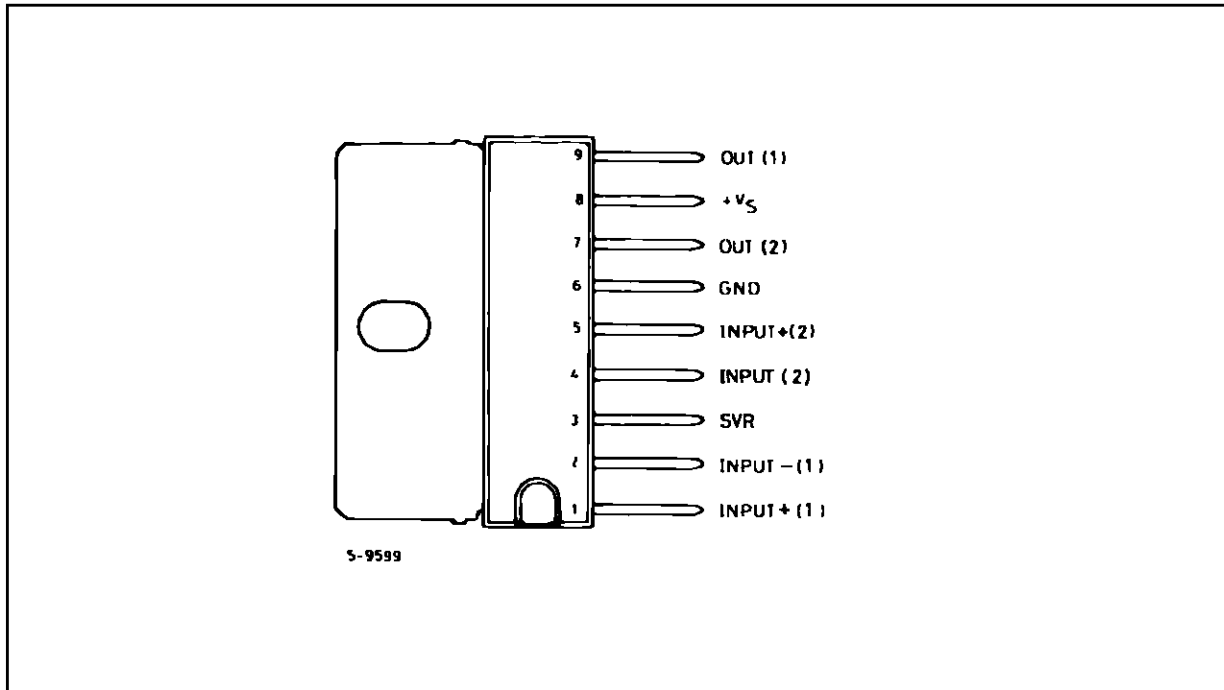


STEREO TEST CIRCUIT

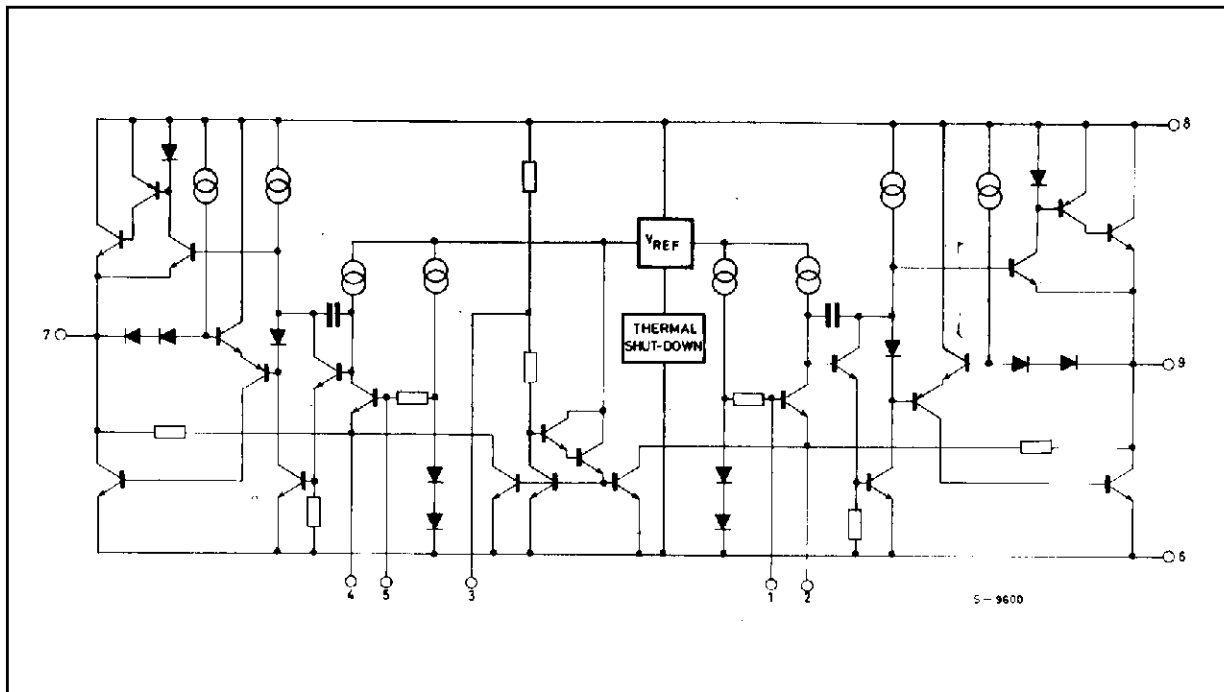


TDA2007A

PIN CONNECTION (top view)



SCHEMATIC DIAGRAM



THERMAL DATA

| Symbol | Parameter | Value | Unit |
|--------|-----------|-------|------|
|--------|-----------|-------|------|

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-----------------------------------|--|------------|------|
| V _S | Supply Voltage | 28 | V |
| I _O | Output Peak Current (repetitive f ≥ 20Hz) | 3 | A |
| I _O | Output Peak Current (non repetitive t = 100μs) | 3.5 | A |
| P _{tot} | Power Dissipation at T _{case} = 70°C | 10 | W |
| T _{stg} , T _j | Storage and Junction Temperature | -40 to 150 | °C |

ELECTRICAL CHARACTERISTICS (refer to the stereo application circuit, T_{amb} = 25°C, V_S = 18V, G_V = 36dB, unless otherwise specified)

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Unit |
|-----------------|---|--|------------|-------------|------|----------|
| V _S | Supply Voltage | | 8 | | 26 | V |
| V _O | Quiescent Output Voltage | | | 8.5 | | V |
| I _d | Total Quiescent Drain Current | | | 50 | 90 | mA |
| P _O | Output Power (each channel) | f = 100Hz to 6KHz d = 0.5% V _S = 18V R _L = 4Ω V _S = 22V R _L = 8Ω | 5.5 5.5 | 6 6 | | W W |
| d | Distortion (each channel) | f = 1KHz, V _S = 18V, R _L = 4Ω P _O = 100mW to 3W f = 1KHz, V _S = 22V, R _L = 8Ω P _O = 100mW to 3W | | 0.1 0.05 | | % % |
| CT | Cross Talk (°°°) | R _L = ∞, R _g = 10KΩ f = 1KHz f = 10KHz | 50 40 | 60 50 | | dB dB |
| V _i | Input Saturation Voltage (rms) | | 300 | | | mV |
| R _i | Input Resistance | f = 1KHz | 70 | 200 | | KΩ |
| f _L | Low Frequency Roll Off (-3dB) | R _L = 4Ω, C ₁₀ = C ₁₁ = 2200μF | | 40 | | Hz |
| f _H | Low Frequency Roll Off (-3dB) | | | 80 | | KHz |
| G _V | Voltage Gain (closed loop) | f = 1KHz | 35.5 | 36 | 36.5 | dB |
| ΔG _V | Closed Loop Gain Matching | | | 0.5 | | dB |
| e _N | Total Input Noise Voltage | R _g = 10kΩ (°) R _g = 10kΩ (°°) | | 1.5 2.5 | 8 | μV μV |
| SVR | Supply Voltage Rejection (each channel) | R _g = 10KΩ f _{ripple} = 100Hz, V _{ripple} = 0.5V | | 55 | | dB |
| T _j | Thermal Shut-down Junction Temperature | | | 145 | | °C |

(°) Curve A. (°°) 22Hz to 22KHz.

TDA2007A

Figure 1 : Stereo Test Circuit ($G_v = 36 \text{ dB}$).

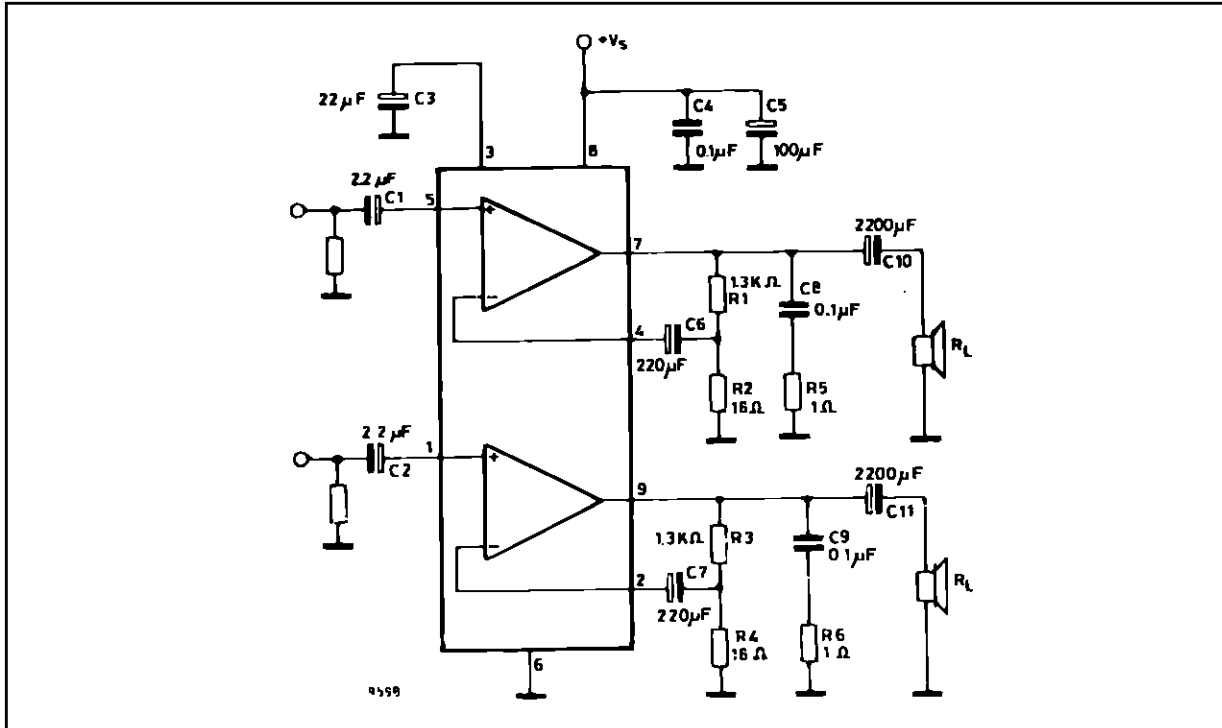
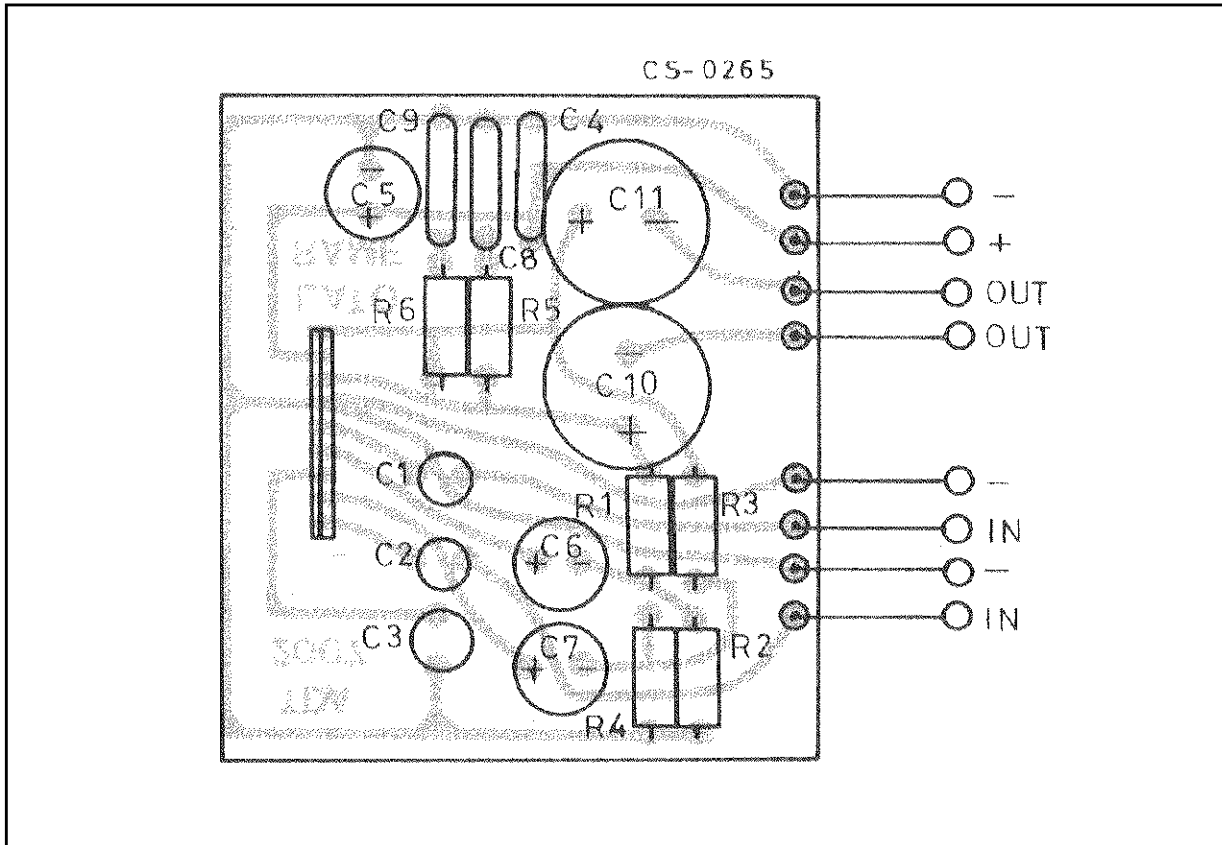


Figure 2 : P.C. Board and Components layout of the Circuit of Fig.1 (1 : 1 scale).



APPLICATION SUGGESTION

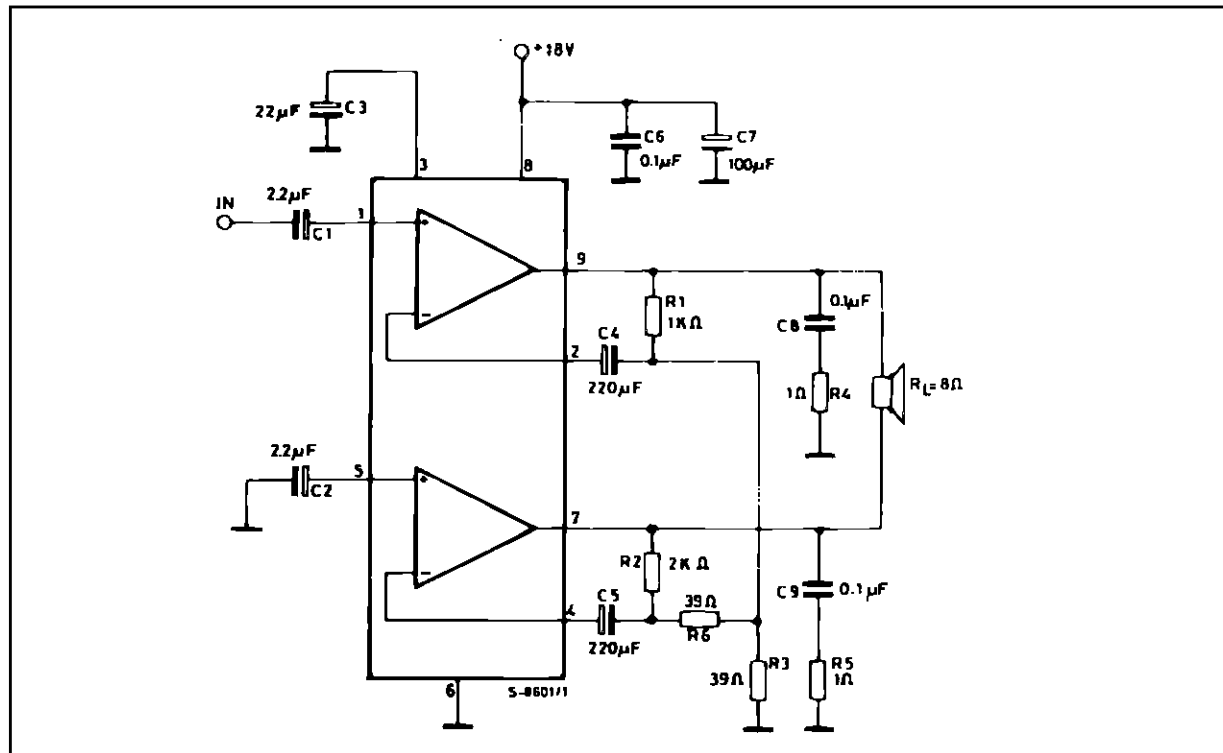
The recommended values of the components are those shown on application circuit of fig.1. Different values can be used ; the following table can help the designer.

| Component | Recommended value | Purpose | Larger Than | Smaller Than |
|-----------|-------------------|------------------------------|---|---|
| R1, R3 | 1.3K Ω | Close Loop Gain Setting (*) | Increase of Gain | Decrease of Gain |
| R2 and R4 | 18 Ω | | Decrease of Gain | Increase of gain |
| R5 and R6 | 1 Ω | Frequency stability | Danger of Oscillation at High Frequency with Inductive Load | |
| C1 and C2 | 2.2 μ F | Input DC Decoupling | High Turn-on Delay | High Turn-on Pop Higher Low Frequency Cutoff. Increase of Noise |
| C3 | 22 μ F | Ripple Rejection | Better SVR Increase of the Switch-on Time | Degradation of SVR |
| C6 and C7 | 220 μ F | Feedback Input DC Decoupling | | |
| C8 and C9 | 0.1 μ F | Frequency Stability | | Danger of Oscillation |

(*) The closed loop gain must be higher than 26 dB.

APPLICATION INFORMATION

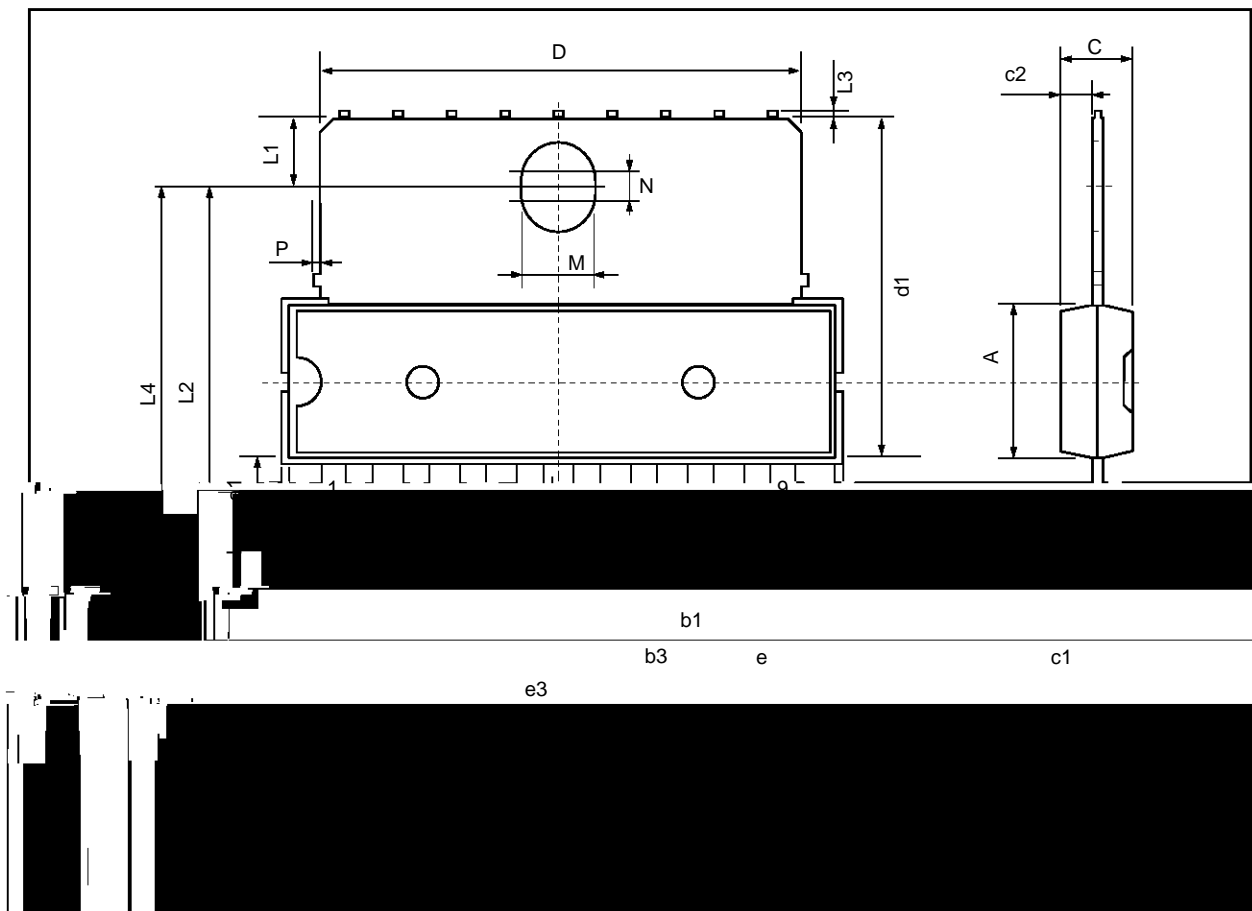
Figure 3 : 12 W Bridge Amplifier (d = 0.5%, G_V = 40 dB).



TDA2007A

SIP9 PACKAGE MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------|-------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 7.1 | | | 0.280 |
| a1 | 2.7 | | 3 | 0.106 | | 0.118 |
| B | | | 23 | | | 0.90 |
| B3 | | | 24.8 | | | 0.976 |
| b1 | | 0.5 | | | 0.020 | |
| b3 | 0.85 | | 1.6 | 0.033 | | 0.063 |
| C | | 3.3 | | | 0.130 | |
| c1 | | 0.43 | | | 0.017 | |
| c2 | | 1.32 | | | 0.052 | |
| D | | | 21.2 | | | 0.835 |
| d1 | | 14.5 | | | 0.571 | |
| e | | 2.54 | | | 0.100 | |
| e3 | | 20.32 | | | 0.800 | |
| L | 3.1 | | | 0.122 | | |
| L1 | | 3 | | | 0.118 | |
| L2 | | 17.6 | | | 0.693 | |
| L3 | | | 0.25 | | | 0.010 |
| L4 | 17.4 | | 17.85 | 0.685 | | 0.702 |
| M | | 3.2 | | | 0.126 | |
| N | | 1 | | | 0.039 | |
| P | | | 0.15 | | | 0.006 |



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